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Product data sheet

1. General description

AC Thyristor power switch in a SOT223 surface-mountable plastic package with self-protective capabilities against low and high energy transients.

2. Features and benefits

- Common terminal on mounting base allows multiple ACTs on shared cooling pad
- Exclusive negative gate triggering
- Full cycle AC conduction
- High voltage capability
- · Remote gate separates the gate driver from the effects of the load current
- Safe clamping of low energy over-voltage transients
- · Self-protective turn-on during high energy voltage transients
- Surface-mountable package
- Very high noise immunity

3. Applications

- Fan motor circuits
- Pump motor circuits
- Lower-power highly inductive, resistive and safety loads
- · Contactors, circuit breakers, valves, dispensers and door locks

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 112 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	0.8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	13	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 16.7 ms	-	-	14.3	A
Tj	junction temperature		-	-	125	°C
V _{PP}	peak pulse voltage	T_j = 25 °C; non-repetitive, off-state; ten pulses on each voltage polarity; 20s or more between successive pulses; Fig. 6	-	-	2.5	kV

ACT108W-800E

AC Thyristor power switch

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 10</u>	1	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 10</u>	1	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 12</u>	-	-	20	mA
V _T	on-state voltage	I _T = 1.1 A; T _j = 25 °C; <u>Fig. 13</u>	-	-	1.3	V
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic cl	haracteristics	·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 15	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$ V_D = 400 \text{ V}; \text{T}_\text{j} = 125 ^\circ\text{C}; \\ I_{\text{T(RMS)}} = 0.8 \text{A}; \text{dV}_{\text{com}}/\text{dt} = 20 \text{V/} \mu\text{s}; \\ (\text{snubberless condition}); \text{ gate open circuit; } \text{Fig. 16; Fig. 17} $	0.5	-	-	A/ms

5. Pinning information

Table 2. Pinning information

	in ing in	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	LD	load	4	LD
2	СМ	common		_ 🕸
3	G	gate		G −o ⊢
4	СМ	common	⊟1 ⊟2 ⊟3 SC-73 (SOT223)	CM 001aaj924

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
ACT108W-800E	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223				

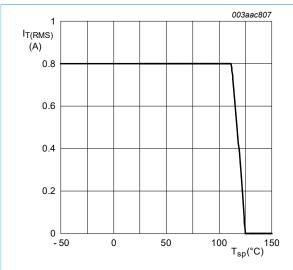


7. Limiting values

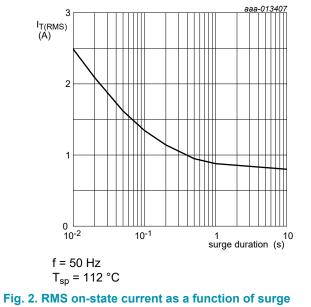
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 112 °C; <u>Fig. 1; Fig. 2;</u> <u>Fig. 3</u>	-	0.8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	13	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	14.3	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.84	A²s
dl _T /dt	rate of rise of on-state current	I _G = 20 mA	-	100	A/µs
I _{GM}	peak gate current	t = 20 µs	-	1	А
V _{GM}	peak gate voltage	positive applied gate voltage	-	15	V
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T_j = 25 °C; non-repetitive, off-state; ten pulses on each voltage polarity; 20s or more between successive pulses; Fig. 6	-	2.5	kV

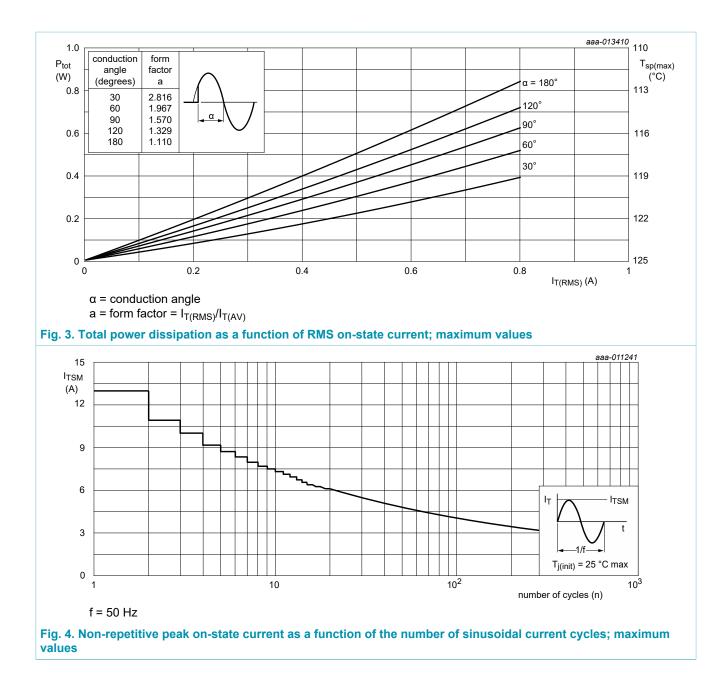






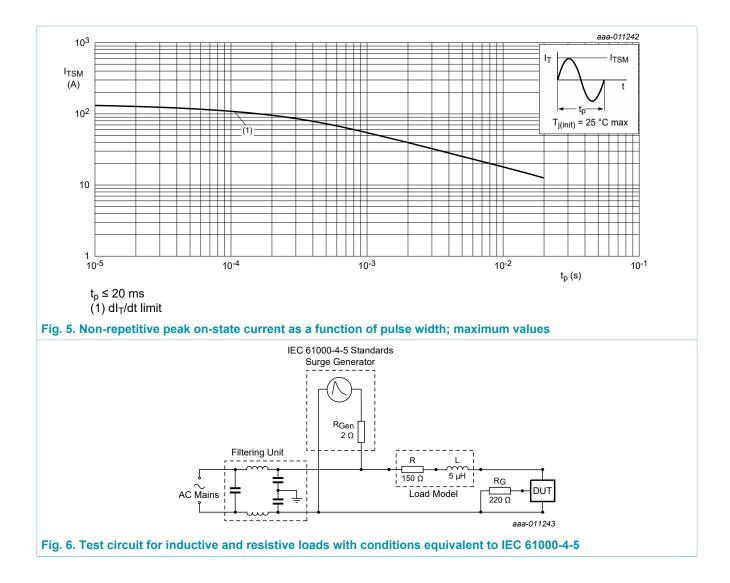


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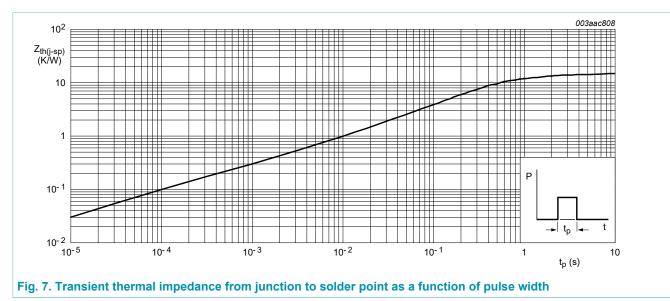




AC Thyristor power switch

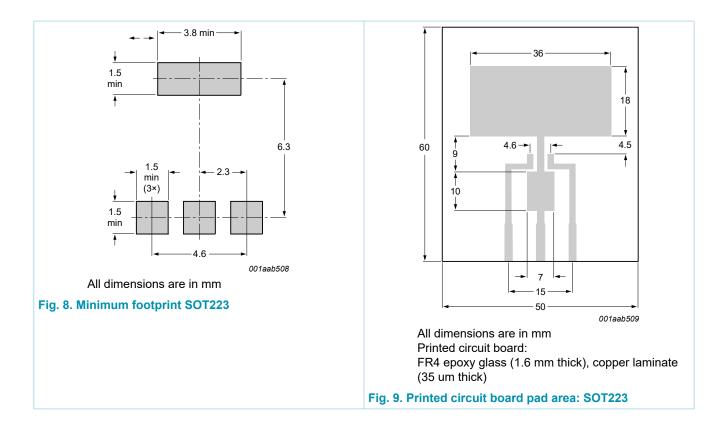
8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	full cycle with heatsink compound;; Fig. 7	-	-	15	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air; printed circuit board mounted; minimum footprint; <u>Fig. 8</u>	-	156	-	K/W
		in free air; printed circuit board mounted; pad area; <u>Fig. 9</u>	-	70	-	K/W



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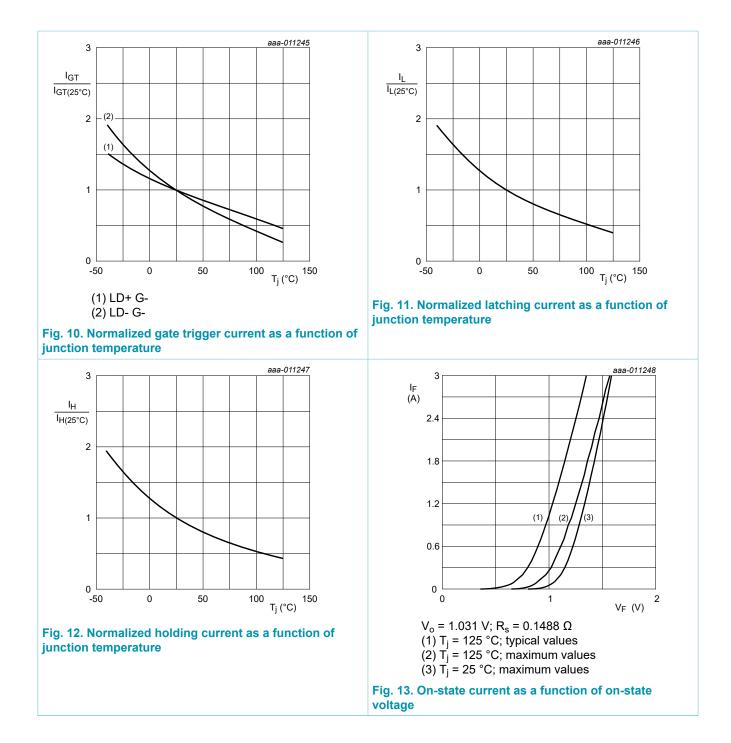
AC Thyristor power switch

9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 10</u>	1	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 10</u>	1	-	10	mA
IL	latching current	V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 11</u>	-	-	25	mA
		V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 11</u>	-	-	20	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 12</u>	-	-	20	mA
V _T	on-state voltage	I _T = 1.1 A; T _j = 25 °C; <u>Fig. 13</u>	-	-	1.3	V
V _{GT}	gate trigger voltage	V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 14	0.15	-	-	V
		V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 14	-	-	1	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	2	μA
		V _D = 800 V; T _j = 125 °C	-	-	0.2	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	aracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 15	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C};$ $I_{T(RMS)} = 0.8 \text{ A}; dV_{com}/dt = 20 \text{ V/}\mu\text{s};$ (snubberless condition); gate open circuit; Fig. 16; Fig. 17	0.5	-	-	A/ms

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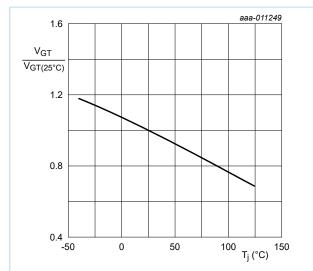
AC Thyristor power switch



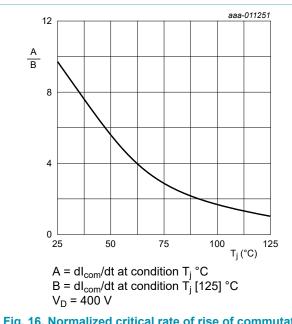
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ACT108W-800E

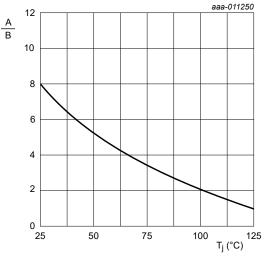
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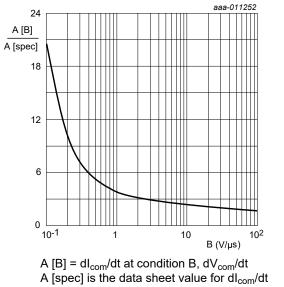






A = dV_D/dt at condition T_j °C B = dV_D/dt at condition T_i [125] °C





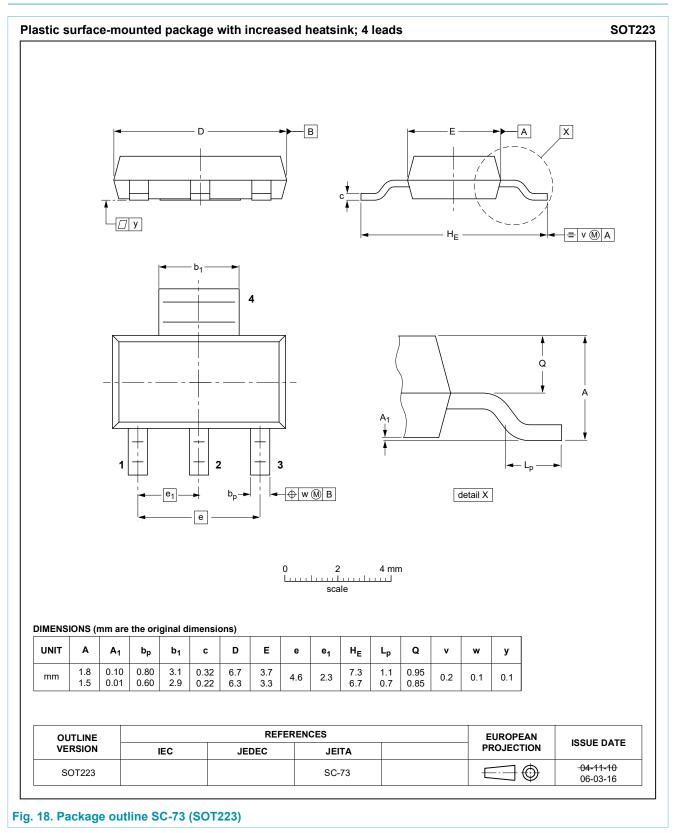
turn-off time is less than 20 ms Fig. 17. Normalized critical rate of change of commutating current as a function of critical rate of

change of commutating voltage; minimum values



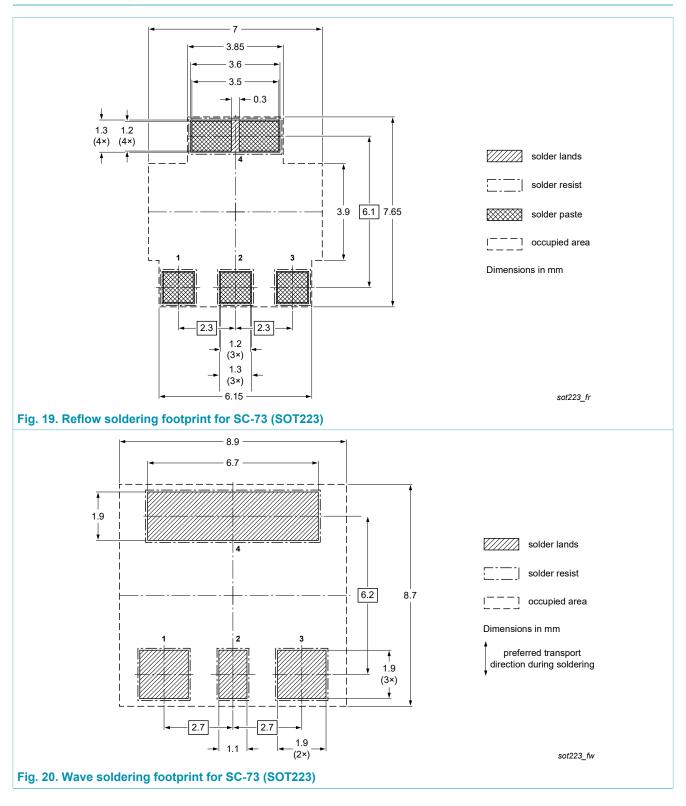
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10. Package outline



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11. Soldering



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12. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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